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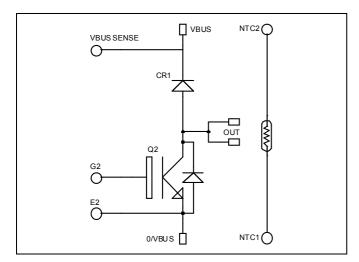




Boost chopper Trench + Field Stop IGBT3 Power Module

$$V_{CES} = 1700V$$

 $I_C = 50A$ @ $Tc = 80$ °C

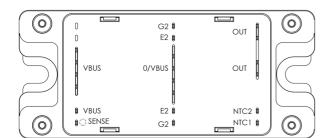


Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration
- Internal thermistor for temperature monitoring



Benefits

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1700	V
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	75	
	Continuous Conector Current	$T_C = 80$ °C	50	A
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	100	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	312	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	100A @ 1600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				250	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		2.0	2.4	V
		$I_C = 50A$ $T_j = 125$	$T_j = 125$ °C		2.4		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1 \text{mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Condition	Min	Typ	Max	Unit	
Cies	Input Capacitance	$\begin{aligned} V_{GE} &= 0V \\ V_{CE} &= 25V \\ f &= 1MHz \end{aligned}$			4400		
C_{oes}	Output Capacitance				180		pF
C_{res}	Reverse Transfer Capacitance				150		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			370		
T_{r}	Rise Time	$V_{GE} = 15V$			40		ns
$T_{d(off)} \\$	Turn-off Delay Time	$V_{\text{Bus}} = 900V$ $I_{\text{C}} = 50A$			650		
T_{f}	Fall Time	$R_G = 10\Omega$			180		
$T_{d(on)}$	Turn-on Delay Time	Inductive Swit	ching (125°C)		400		
T_{r}	Rise Time	$V_{GE} = 15V$ $V_{Bus} = 900V$			50		ns
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm C} = 50A$			800		115
T_{f}	Fall Time	$R_G = 10\Omega$			300		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 900V$	$T_j = 125$ °C		16	·	m I
E_{off}	Turn-off Switching Energy	$I_C = 50A$ $R_G = 10\Omega$	$T_j = 125$ °C		15		mJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1700			V
I_{RM}	Mayimayan Dayanga Laakaga Cymmant	V _R =1700V	$T_j = 25^{\circ}C$			250	Δ
1 _{RM}	Maximum Reverse Leakage Current	V _R -1700 V	$T_j = 125$ °C			500	μA
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		50		A
$V_{\rm F}$	Diode Forward Voltage	de Forward Voltage $I_F = 50A$	$T_i = 25^{\circ}C$		1.8	2.2	V
v F	Diode Polward Voltage		$T_i = 125$ °C		1.9		v
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		385		ns
·rr	Reverse Recovery Time		$T_j = 125$ °C		490		113
	Reverse Recovery Charge	$I_F = 50A$ $V_R = 900V$ $di/dt = 800A/\mu s$	$T_j = 25^{\circ}C$		14		μС
Q_{rr}	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		23		μС
Б	Davanca Dagayami Emanayi	•	$T_j = 25^{\circ}C$		6		mJ
E _r	Reverse Recovery Energy		$T_j = 125$ °C		12		1117



 $Temperature \ sensor \ NTC \ (see \ application \ note \ APT0406 \ on \ www.microsemi.com \ for \ more \ information).$

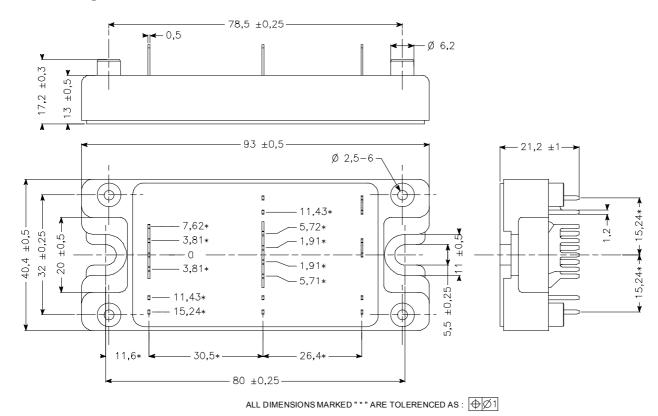
Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_T = \frac{R_{25}}{\exp \left[\frac{1}{R_{25/85}} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$
 R_T: Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance	IGBT Diode			0.4	°C/W	
					0.7	C/ W	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

SP4 Package outline (dimensions in mm)

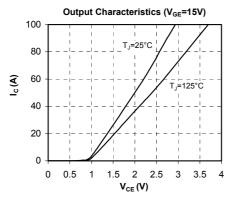


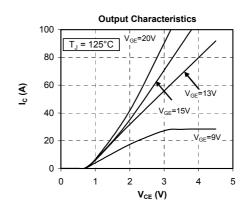
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

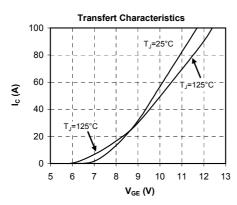
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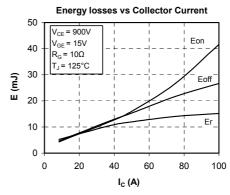


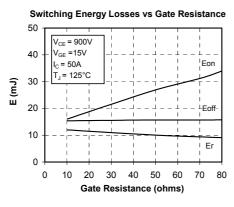
Typical Performance Curve

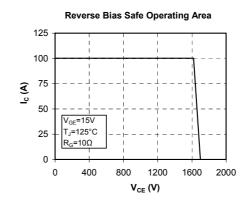


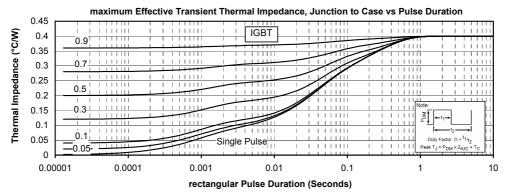




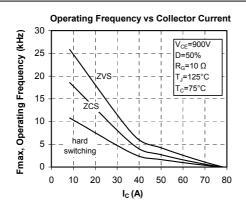


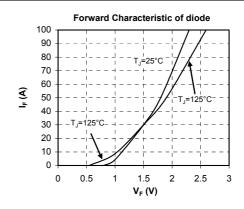


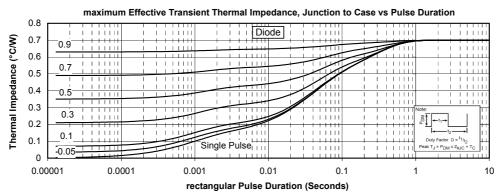












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